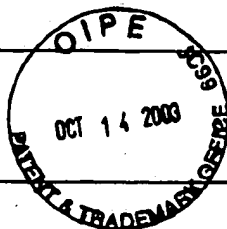


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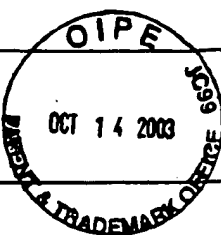
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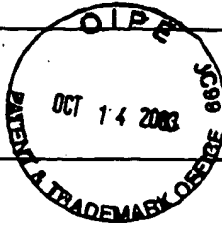
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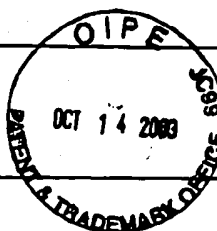
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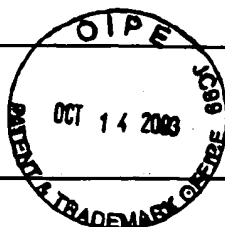
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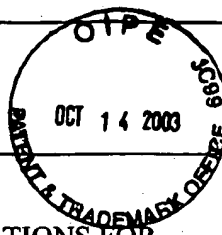
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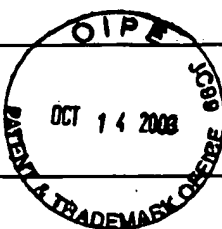
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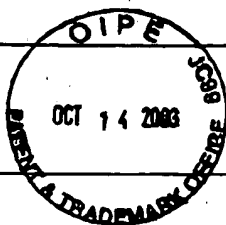
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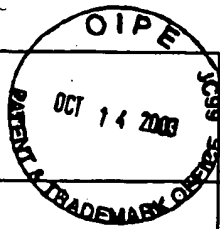
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Applicant: Bernard Q. Li

Filing Date:
July 18, 2003

Group Art:
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